



60V P-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	R _{DS(ON)}	I _D Tc = +25°C	
-60V	18mΩ @ V _{GS} = -10V	-60A	
-60 V	26mΩ @ V _{GS} = -4.5V	-50A	

Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- DC-DC Converters
- Load Switch

Features and Benefits

- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low RDS(ON) Minimizes On State Losses
- Low Input Capacitance
- Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

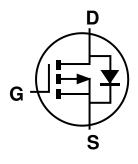
https://www.diodes.com/products/automotive/automotive-products/.

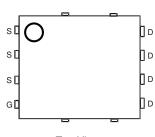
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.
 - https://www.diodes.com/quality/product-definitions/
- An Automotive-Compliant Part is Available Under Separate Datasheet (<u>DMP6018LPSQ</u>)

Mechanical Data

- Case: PowerDI[®]5060-8
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 63
- Weight: 0.097 grams (Approximate)







Internal Schematic

Top View Pin Configuration

Ordering Information (Note 4)

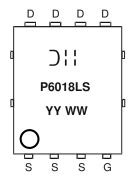
Part Number	Case	Packaging	
DMP6018LPS-13	PowerDI5060-8	2,500 / Tape & Reel	

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information



);; = Manufacturer's Marking P6018LS = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 21 = 2021) WW = Week (01 to 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			VDSS	-60	V
Gate-Source Voltage			Vgss	±20	V
Continuous Drain Current, VGS = -10V (Note 6)	Steady State	$T_C = +25^{\circ}C$ $T_C = +70^{\circ}C$	lo	-60 -48	Α
Maximum Continuous Body Diode Forward Current	Is	-60	Α		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			I _{DM}	-240	Α
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)			lsм	-240	Α
Avalanche Current, L = 0.3mH			las	-47	Α
Avalanche Energy, L = 0.3mH			Eas	331	mJ

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	P_{D}	2.6	W
Thermal Resistance, Junction to Ambient (Note 5)	R _θ JA	50	°C/W	
Total Power Dissipation (Note 6) $T_C = +25^{\circ}C$		P_{D}	113	W
Thermal Resistance, Junction to Case (Note 6)		Rejc	1.1	°C/W
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C

5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate. 6. Thermal resistance from junction to soldering point (on the exposed drain pad). Notes:

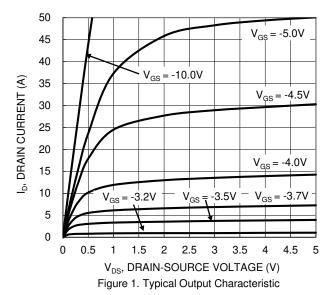


Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	-60	_	_	V	$V_{GS} = 0V, I_{D} = -250\mu A$	
Zero Gate Voltage Drain Current	IDSS	_	_	-1	μA	V _{DS} = -60V, V _{GS} = 0V	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(TH)}	-1.5	_	-2.5	V	$V_{DS} = V_{GS}$, $I_D = -250\mu A$	
Static Drain-Source On-Resistance		_	13	18	mΩ	$V_{GS} = -10V, I_{D} = -17A$	
Static Drain-Source On-nesistance	Rds(on)	_	22	26	11122	$V_{GS} = -4.5V, I_{D} = -5A$	
Diode Forward Voltage	V _{SD}	_	-0.76	-1.0	V	V _{GS} = 0V, I _S = -17A	
DYNAMIC CHARACTERISTICS (Note 8)						•	
Input Capacitance	Ciss	_	3505	_		V _{DS} = -30V, V _{GS} = 0V, f = 1MHz	
Output Capacitance	Coss	_	516	_	pF		
Reverse Transfer Capacitance	Crss	_	200	_			
Gate Resistance	Rg	_	9.1	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (VGS = -4.5V)	Qg	_	7.1	_		V _{DS} = -30V, I _D = -10A	
Total Gate Charge (V _{GS} = -10V)	Qg	_	13.7	_	nC		
Gate-Source Charge	Q _{gs}	_	1.8	_	IIC		
Gate-Drain Charge	Qgd	_	3.5	_			
Turn-On Delay Time	t _{D(ON)}	_	3.9	_		$V_{DD} = -30V$, $V_{GS} = -10V$, $I_{D} = -10A$, $R_{G} = 2.5\Omega$	
Turn-On Rise Time	tr	_	6.7	_	20		
Turn-Off Delay Time	tD(OFF)	_	16.0	_	ns		
Turn-Off Fall Time	tr	_	7.2	_			
Body Diode Reverse Recovery Time	trr	_	32	_	ns	lo 174 di/dt 1004/up	
Body Diode Reverse Recovery Charge	Qrr	_	28	_	nC	-Is = -17A, di/dt = 100A/μs	

7. Short duration pulse test used to minimize self-heating effect. 8. Guaranteed by design. Not subject to product testing. Notes:





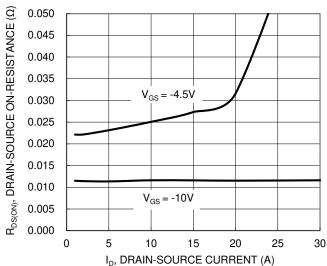


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

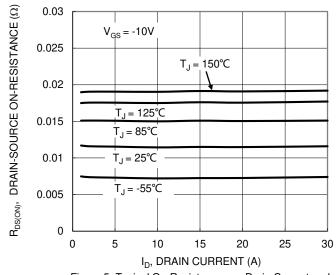


Figure 5. Typical On-Resistance vs. Drain Current and Temperature

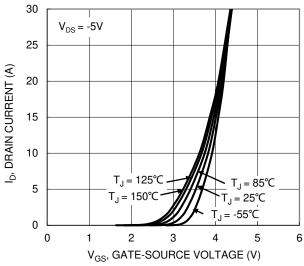


Figure 2. Typical Transfer Characteristic

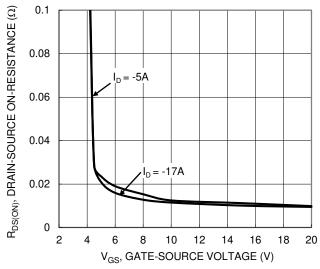


Figure 4. Typical Transfer Characteristic

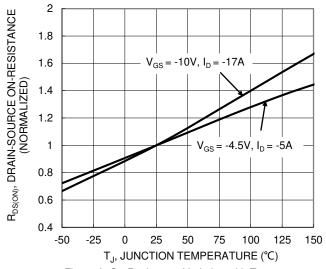


Figure 6. On-Resistance Variation with Temperature



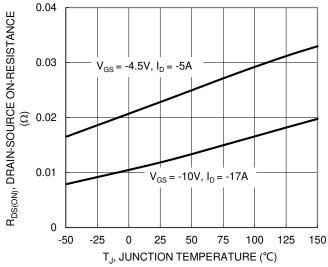


Figure 7. On-Resistance Variation with Temperature

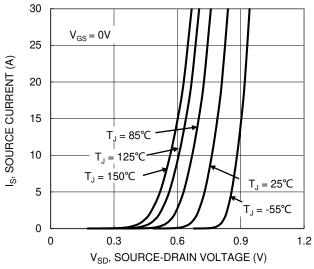
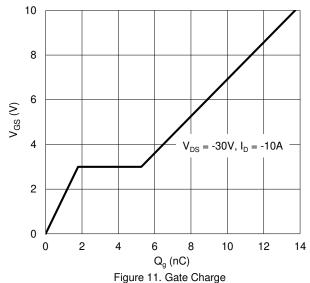
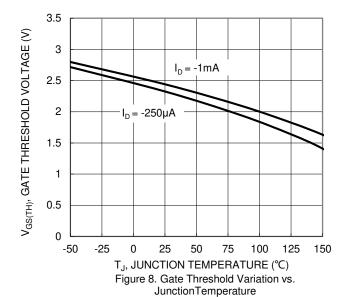
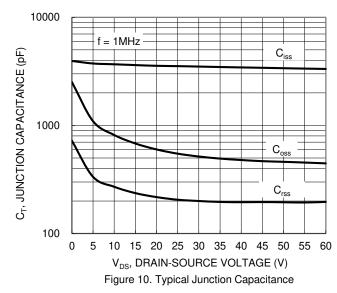


Figure 9. Diode Forward Voltage vs. Current







1000 R_{DS(ON)} Limited 100 ID, DRAIN CURRENT (A) $P_{W} = 100 \mu s$ 10 $T_{J(Max)} = 150$ °C = 10ms $T_C = 25^{\circ}C$ $P_W = 100 ms$ Single Pulse DUT on Infinite Heatsink $V_{GS} = -10V$ 0.1 0.1 10 100 V_{DS}, DRAIN-SOURCE VOLTAGE (V) Figure 12. SOA, Safe Operation Area



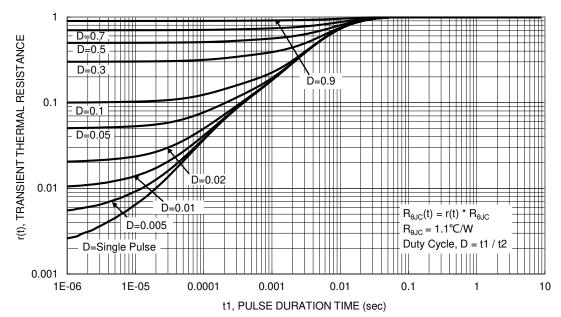


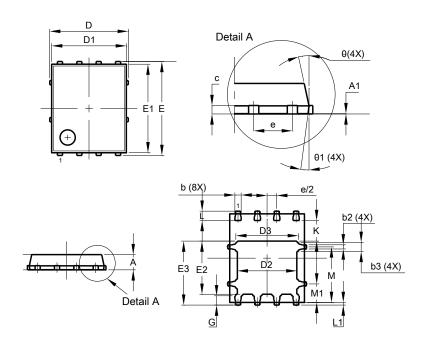
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8

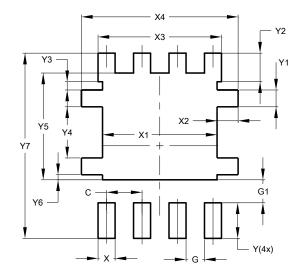


PowerDI5060-8						
Dim	Min	Max	Тур			
Α	0.90 1.10 0.00 0.05		1.00			
A 1	0.00	-				
b	0.33	0.51	0.41			
b2	0.200	0.350	0.273			
b3	0.40	0.80	0.60			
C	0.230	0.330	0.277			
D		5.15 BSC	;			
D1	4.70	5.10	4.90			
D2	3.70	4.10	3.90			
D3	3.90	3.90 4.30 4.10				
Е		6.15 BSC				
E1	5.60	6.00	5.80			
E2	3.28	3.68	3.48			
E3	3.99	4.39	4.19			
е		1.27 BSC				
G	0.51	0.71	0.61			
K	0.51	_	-			
L	0.51	0.71	0.61			
L1	0.100	0.200	0.175			
M	3.235	4.035	3.635			
M1	1.00	1.40	1.21			
Θ	10°	12°	11°			
Θ1	6°	8°	7°			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8



Dimensions	Value (in mm)			
С	1.270			
G	0.660			
G1	0.820			
X	0.610			
X1	4.100			
X2	0.755			
Х3	4.420			
X4	5.610			
Υ	1.270			
Y1	0.600			
Y2	1.020			
Y3	0.295			
Y4	1.825			
Y5	3.810			
Y6	0.180			
Y7	6.610			

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